1-of-2 Non-Inverting Demultiplexer with 3-State Deselected Output

The NL7SZ18 is a high–performance 1–to–2 Demultiplexer operating from a 1.65 V to 5.5 V supply. When the select pin [S] is enabled [high or low], the data in the address pin [A] is routed to one of the output pins [Y_0 or Y_1], maintaining a high–impedance on the deselected output pin (See Truth Table).

This device has been optimized for on-board buffering applications and offers mixed (1.65 V, 2.3 V, 3.0 V and 5.5 V) voltage capability by providing over voltage tolerance (OVT*) circuitry on I/O pins.

Features

- High–Speed Propagation Delay
 tPD 2.5 nS (Typ), Load 50 pF @ 5.0 V
- Power Down Impedance Outputs in High–Z
- Output Drive Capability 32 mA @ 5.0 V
- Broad V_{CC} Operating Range 1.65 V to 5.5 V
- Surface Mount Technology SC-70, 6-Lead Packaging
- OVT* on Inputs / Outputs

Typical Applications

- Cell Phones
- PDAs
- Digital Cameras
- Video Cameras

Important Information

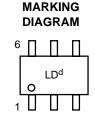
- ESD Protection: MM >200 V, HBM >2000 V
- Latch-Up Max Rating: 300 mA
- Pin to Pin Compatible with NC7SZ18



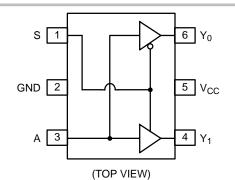
ON Semiconductor®

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LD = Device Marking d = Date Code



PIN/FUNCTION TABLE

| Pin | Function |
|----------------|----------------------|
| А | Data Input |
| S | Demultiplexer Select |
| Y ₀ | Output 1 |
| Y ₁ | Output 2 |

TRUTH TABLE

| Inp | out | Out | put |
|-----|-----|----------------|----------------|
| S | Α | Y ₀ | Y ₁ |
| L | L | L | Z |
| L | Н | Н | Z |
| Н | L | Z | L |
| Н | Н | Z | Н |

ORDERING INFORMATION

| Device | Package | Shipping [†] |
|-------------|---------|-----------------------|
| NL7SZ18DFT2 | SC70-6 | 3000 / Tape & Reel |

[†]For information on tape and reel specifications, including part orientation and tape sizes, please refer to our Tape and Reel Packaging Specification Brochure, BRD8011/D.

^{*}Over Voltage Tolerance (OVT) enables input and output pins to function outside (higher) of their operating voltages, with no damage to the devices or to signal integrity.

NL7SZ18

MAXIMUM RATINGS

| Symbol | Rating | | Value | Unit | |
|-------------------|---|--|---------------------|------|--|
| V _{CC} | DC Supply Voltage | -0.5 to +7.0 | V | | |
| V _{IN} | DC Input Voltage | | -0.5 to +7.0 | V | |
| V _{OUT} | DC Output Voltage | | -0.5 to +7.0 | V | |
| I _{IK} | DC Input Diode Current | @ V ₁ < -0.5 V | -50 | mA | |
| I _{OK} | DC Output Diode Current | @ V ₁ < -0.5 V | -50 | mA | |
| I _{OUT} | DC Output Sink Current | | ±50 | mA | |
| I _{CC} | DC Supply Current per Supply Pin | | ±100 | mA | |
| I _{GND} | DC Ground Current per Ground Pin | ±100 | mA | | |
| T _{STG} | Storage Temperature Range | -65 to +150 | °C | | |
| TL | Lead Temperature, 1 mm from Case for 10 Secon | 260 | °C | | |
| TJ | Junction Temperature Under Bias | | +150 | °C | |
| $\theta_{\sf JA}$ | Thermal Resistance (Note 1) | | 250 | °C/W | |
| P_{D} | Power Dissipation in Still Air at 85°C | | 180 | mW | |
| MSL | Moisture Sensitivity | | Level 1 | _ | |
| F _R | Flammability Rating Oxygen Index: 28 to 34 | | UL 94 V-0 @ 0125 in | _ | |
| V _{ESD} | ESD Withstand Voltage | Human Body Model (Note 2) Machine Model (Note 3) Charged Device Model (Note 4) | | | |

Maximum Ratings are those values beyond which damage to the device may occur. Exposure to these conditions or conditions beyond those indicated may adversely affect device reliability. Functional operation under absolute maximum—rated conditions is not implied. Functional operation should be restricted to the Recommended Operating Conditions.

1. Measured with minimum pad spacing on an FR4 board, using 10 mm—by–1 inch, 2 ounce copper trace no air flow.

- Tested to EIA/JESD22-A114-A.
 Tested to EIA/JESD22-A115-A.
- 4. Tested to JESD22-C101-A.

RECOMMENDED OPERATING CONDITIONS

| Symbol | Rating | | Value | Unit |
|---------------------------------|-----------------------------------|---|---|------|
| V _{CC} | DC Supply Voltage | | 1.65 to 5.5 | V |
| V _{CC} | DC Supply Voltage, Data Retention | 1.5 to 5.5 | V | |
| V _{IN} | Input Voltage | | 0 to 5.5 | V |
| V _{OUT} | Output Voltage | | 0 to 5.5 | V |
| T _A | Operating Temperature | | -40 to 85 | °C |
| t _r , t _f | Input Rise and Fall Times | $\begin{array}{c} V_{CC} @ 1.8 \pm 0.15 \ V \\ V_{CC} @ 2.5 \pm 0.2 \ V \\ V_{CC} @ 3.3 \pm 0.3 \ V \\ V_{CC} @ 5.0 \pm 0.5 \ V \\ \end{array}$ | 0 to 20 0 to 20 0 to 10 0 to 5 | nS/V |
| θ_{JA} | Thermal Resistance | | 350 | °C/W |

NL7SZ18

DC ELECTRICAL CHARACTERISTICS

| | | Condition | | V _{CC} | T _A = 25°C | | | $T_A = -40^{\circ}C$ to $85^{\circ}C$ | | |
|------------------|------------------------------|----------------------|---|----------------------------------|--|--------------------------------------|--|--|--|------|
| Symbol | Parameter | | | (V) | Min | Тур | Max | Min | Max | Unit |
| V _{IH} | High-Level Input Voltage | | | 1.65–1.95 2.3–5.5 | 0.75 V _{CC} 0.70 V _{CC} | | | 0.75 V _{CC} 0.70 V _{CC} | | V |
| V_{IL} | Low-Level Output Voltage | | | 1.65–1.95 2.3–5.5 | | | 0.25 V _{CC} 0.30 V _{CC} | | 0.25 V _{CC} 0.30 V _{CC} | V |
| | | | I _{OH} = -100 μa | 1.65 2.3 3.0 4.5 | 1.55 2.20 2.90 4.40 | 1.65 2.30 3.00 4.50 | | 1.55 2.20 2.90 4.40 | | |
| V _{OH} | High-Level Output Voltage | $V_{IN} = V_{IH}$ | $I_{OH} = -4.0 \text{ mA}$ $I_{OH} = -8.0 \text{ mA}$ $I_{OH} = -16 \text{ mA}$ $I_{OH} = -24 \text{ mA}$ $I_{OH} = -32 \text{ mA}$ | 1.65 2.3 3.0 3.0 4.5 | 1.29 1.90 2.40 2.30 3.80 | 1.52 2.15 2.80 2.68 4.20 | | 1.29 1.90 2.40 2.30 3.80 | | V |
| | Low-Level | | I _{OL} = 100 μa | 1.65 2.3 3.0 4.5 | | 0.0 0.0 0.0 0.0 | 0.10 0.10 0.10 0.10 | | 0.10 0.10 0.10 0.10 | |
| V _{OL} | Output Voltage | $V_{IN} = V_{IL}$ | $I_{OL} = 4.0 \text{ mA}$ $I_{OL} = 8.0 \text{ mA}$ $I_{OL} = 16 \text{ mA}$ $I_{OL} = 24 \text{ mA}$ $I_{OL} = 32 \text{ mA}$ | 1.65 2.3 3.0 3.0 4.5 | | 0.08 0.10 0.15 0.22 0.22 | 0.24 0.30 0.40 0.55 0.55 | | 0.24 0.30 0.40 0.55 0.55 | V |
| I _{IN} | Input Leakage Current | V _{IN} = 5 | 5.5 V, GND | 0.0 to 5.5 | | | ± 0.1 | | ±1.0 | μΑ |
| l _{OZ} | Output High-Z Current | | V_{IH} or V_{IL} out $\leq 5.5 \text{ V}$ | 1.65 to 5.5 | | | ±0.5 | | ±5.0 | μΑ |
| I _{OFF} | Power–Off Leakage Current | V _{IN} or \ | V _{CC} = 5.5 V | 0.0 | | | 1.0 | | 10 | μΑ |
| I _{CC} | Quiescent Supply Current | V _{IN} = 5 | 5.5 V, GND | 1.8 to 5.5 | | | 1.0 | | 10 | μΑ |

AC ELECTRICAL CHARACTERISTICS

| | | | | T _A = 25°C | | T _A = -40°C to 85°C | | | | |
|--------------------------------------|---------------------------------------|---|--|--------------------------|--------------------------|-----------------------------------|--------------------------|---------------------------|------|------------------|
| Symbol | Parameter | Condition | V _{CC} | Min | Тур | Max | Min | Max | Unit | Figure |
| t _{PLH} | Propagation Delay | C_L = 15 pF R_D = 1.0 M Ω S = OPEN | $\begin{array}{c} 1.8 \pm 0.15 \\ 2.5 \pm 0.2 \\ 3.3 \pm 0.3 \\ 5.0 \pm 0.5 \end{array}$ | 2.0 1.0 0.8 0.5 | 6.3 3.6 2.7 2.0 | 10.1 5.7 4.0 3.1 | 2.0 1.0 0.8 0.5 | 10.5 6.0 4.3 3.3 | nS | Figures 1 & 3 |
| t _{PHL} | A to Y ₀ or Y ₁ | $C_L = 50 \text{ pF}$ $R_D = 500 \Omega$ $S = OPEN$ | 3.3 ± 0.3 5.0 ± 0.5 | 1.2 0.8 | 3.4 2.5 | 4.9 3.9 | 1.2 0.8 | 5.4 4.2 | nS | Figures 1 & 3 |
| ^t PZL ^t PZH | Output Fachla Time | $C_L = 50 \text{ pF}$ $R_D, R_U = 500 \Omega$ $S = \text{GND for } t_{PZH}$ $S = V_{IN} \text{ for } t_{PZL}$ $V_I = 2 \text{ x } V_{CC}$ | 1.8 ± 0.15 2.5 ± 0.2 3.3 ± 0.3 5.0 ± 0.5 | 3.0 1.8 1.2 0.8 | 6.9 4.2 3.2 2.5 | 12 6.8 5.0 4.0 | 3.0 1.8 1.2 0.8 | 12.5 7.3 5.5 4.3 | nS | Figures 1 & 3 |
| ^t PLZ t _{PHZ} | Output Enable Time | $C_L = 50 \text{ pF}$ $R_D, R_D = 500 \Omega$ $S = \text{GND for } t_{PHZ}$ $S = V_{IN} \text{ for } t_{PLZ}$ $V_I = 2 \text{ x } V_{CC}$ | 1.8 ± 0.15 2.5 ± 0.2 3.3 ± 0.3 5.0 ± 0.5 | 2.5 1.5 0.8 0.3 | 6.0 4.0 2.9 1.8 | 10 6.8 4.9 3.5 | 2.5 1.5 0.8 0.3 | 10.5 7.1 5.3 3.7 | nS | Figures 1 & 3 |
| C _{IN} C _{OUT} | Input Capacitance Output Capacitance | | OPEN 3.3 | | 2.5 4.0 | | | | pF | |
| C _{PD} | Power Dissipation Capacitance | Note 5 | 3.3 5.0 | | 16 19.5 | | | | pF | Figure 2 |

^{5.} C_{PD} is defined as the value of the internal equivalent capacitance which is derived from dynamic operating current consumption (I_{CCD}) at no output loading and operating at 50% duty cycle (see Figure 2). C_{PD} is related to I_{CCD} dynamic operating current by the expression: I_{CCD} = (C_{PD}) (V_{CC}) (f_{IN}) + (I_{CCD}static).

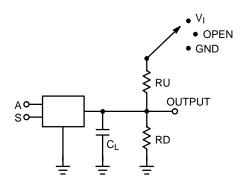


Figure 1. AC Test Circuit

 C_L Includes Load and Stray Capacitance Input PRR = 1.0 MHz; t_W = 500 nS

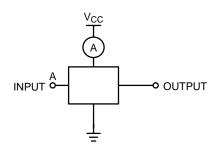
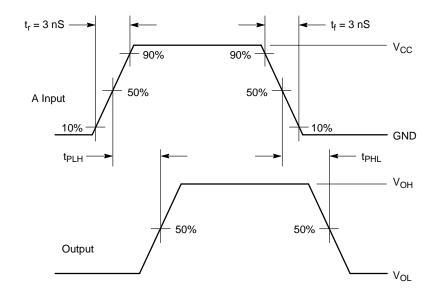


Figure 2. I_{CCD} Test Circuit

 $\begin{aligned} & \text{Input} = \text{AC Waveform; } t_r = t_f = 1.8 \text{ nS} \\ & \text{PRR} = 10 \text{ MHz; } \text{Duty Cycle} = 50\% \\ & \text{S Input} = \text{GND or x} \end{aligned}$



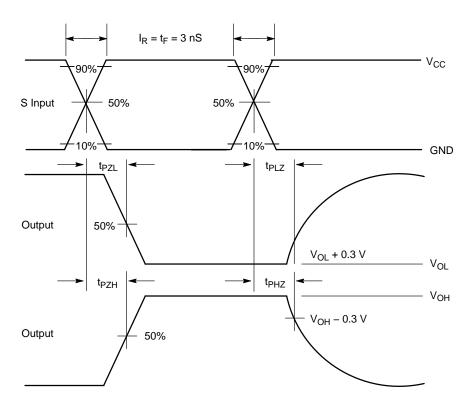


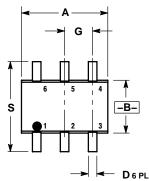
Figure 3. AC Waveforms

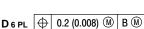
NL7SZ18

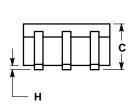
PACKAGE DIMENSIONS

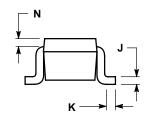
SOT-363/SC70-6/SC-88 **DF SUFFIX**

6-LEAD PACKAGE CASE 419B-02 ISSUE U







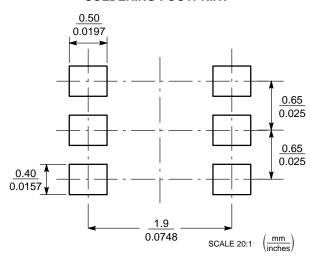


NOTES:

- DIMENSIONING AND TOLERANCING PER ANSI Y14.5M, 1982. CONTROLLING DIMENSION: INCH.
- 419B-01 OBSOLETE, NEW STANDARD 419B-02.

| | INC | HES | MILLIM | ETERS |
|-----|-------|-------|----------|-------|
| DIM | MIN | MAX | MIN | MAX |
| Α | 0.071 | 0.087 | 1.80 | 2.20 |
| В | 0.045 | 0.053 | 1.15 | 1.35 |
| С | 0.031 | 0.043 | 0.80 | 1.10 |
| D | 0.004 | 0.012 | 0.10 | 0.30 |
| G | 0.026 | BSC | 0.65 | BSC |
| Ξ | | 0.004 | | 0.10 |
| ſ | 0.004 | 0.010 | 0.10 | 0.25 |
| K | 0.004 | 0.012 | 0.10 | 0.30 |
| Z | 0.008 | REF | 0.20 REF | |
| S | 0.079 | 0.087 | 2.00 | 2.20 |

SOLDERING FOOTPRINT*



*For additional information on our Pb-Free strategy and soldering details, please download the ON Semiconductor Soldering and Mounting Techniques Reference Manual, SOLDERRM/D.

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